NSN 5961-01-295-5480

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-295-5480 **Inclosure Material:** Metal **Overall Length:** 1.438 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.677 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, dc and 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 50.00 amperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 unthreaded hole **Specification Data:** 53711-6128302 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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